

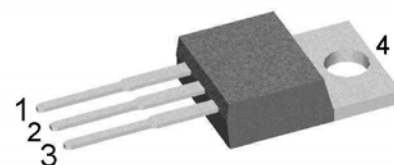
# HiPerFRED<sup>2</sup>

|           |      |       |
|-----------|------|-------|
| $V_{RRM}$ | =    | 200 V |
| $I_{FAV}$ | = 2x | 10 A  |
| $t_{rr}$  | =    | 35 ns |

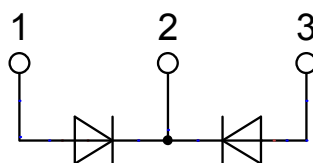
High Performance Fast Recovery Diode  
Low Loss and Soft Recovery  
Common Cathode

Part number

**DPG20C200PB**



Backside: cathode



## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

## Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

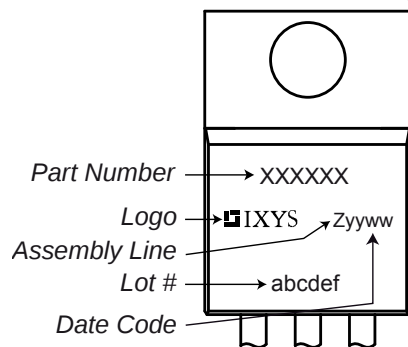
## Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

| Fast Diode |                                              |                                                                                  |                                | Ratings                        |      |      |               |
|------------|----------------------------------------------|----------------------------------------------------------------------------------|--------------------------------|--------------------------------|------|------|---------------|
| Symbol     | Definition                                   | Conditions                                                                       |                                | min.                           | typ. | max. | Unit          |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                                    |                                |                                |      | 200  | V             |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                                    |                                |                                |      | 200  | V             |
| $I_R$      | reverse current, drain current               | $V_R = 200\text{ V}$                                                             | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1    | $\mu\text{A}$ |
|            |                                              | $V_R = 200\text{ V}$                                                             | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 0.06 | mA            |
| $V_F$      | forward voltage drop                         | $I_F = 10\text{ A}$                                                              | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.27 | V             |
|            |                                              | $I_F = 20\text{ A}$                                                              |                                |                                |      | 1.45 | V             |
|            |                                              | $I_F = 10\text{ A}$                                                              | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 0.98 | V             |
|            |                                              | $I_F = 20\text{ A}$                                                              |                                |                                |      | 1.17 | V             |
| $I_{FAV}$  | average forward current                      | $T_C = 150^{\circ}\text{C}$<br>rectangular $d = 0.5$                             | $T_{VJ} = 175^{\circ}\text{C}$ |                                |      | 10   | A             |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                                                |                                | $T_{VJ} = 175^{\circ}\text{C}$ |      | 0.74 | V             |
| $r_F$      | slope resistance                             |                                                                                  |                                |                                |      | 17.7 | m $\Omega$    |
| $R_{thJC}$ | thermal resistance junction to case          |                                                                                  |                                |                                |      | 2.3  | K/W           |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                                                  |                                |                                | 0.50 |      | K/W           |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                                                       |                                |                                |      | 65   | W             |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$               | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 140  | A             |
| $C_J$      | junction capacitance                         | $V_R = 150\text{ V}$ $f = 1\text{ MHz}$                                          | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 15   |      | pF            |
| $I_{RM}$   | max. reverse recovery current                | $I_F = 10\text{ A}; V_R = 130\text{ V}$<br>$-di_F/dt = 200\text{ A}/\mu\text{s}$ | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 3    |      | A             |
|            |                                              |                                                                                  | $T_{VJ} = 125^{\circ}\text{C}$ |                                | 5.5  |      | A             |
|            |                                              |                                                                                  | $T_{VJ} = 25^{\circ}\text{C}$  |                                | 35   |      | ns            |
|            |                                              |                                                                                  | $T_{VJ} = 125^{\circ}\text{C}$ |                                | 45   |      | ns            |
| $t_{rr}$   | reverse recovery time                        |                                                                                  |                                |                                |      |      |               |

| Package TO-220 |                              |                            | Ratings |      |      |      |
|----------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions                 | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal <sup>1)</sup> |         |      | 35   | A    |
| $T_{VJ}$       | virtual junction temperature |                            | -55     |      | 175  | °C   |
| $T_{op}$       | operation temperature        |                            | -55     |      | 150  | °C   |
| $T_{stg}$      | storage temperature          |                            | -55     |      | 150  | °C   |
| Weight         |                              |                            |         | 2    |      | g    |
| $M_D$          | mounting torque              |                            | 0.4     |      | 0.6  | Nm   |
| $F_C$          | mounting force with clip     |                            | 20      |      | 60   | N    |

### Product Marking



### Part number

D = Diode  
 P = HiPerFRED  
 G = extreme fast  
 20 = Current Rating [A]  
 C = Common Cathode  
 200 = Reverse Voltage [V]  
 PB = TO-220AB (3)

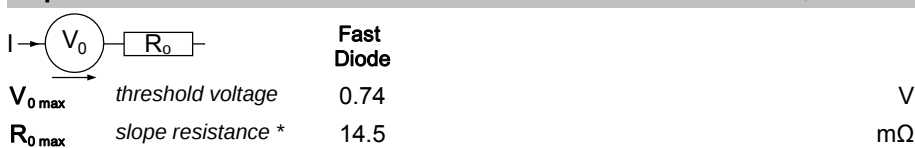
| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | DPG20C200PB | DPG20C200PB        | Tube          | 50       | 506308   |

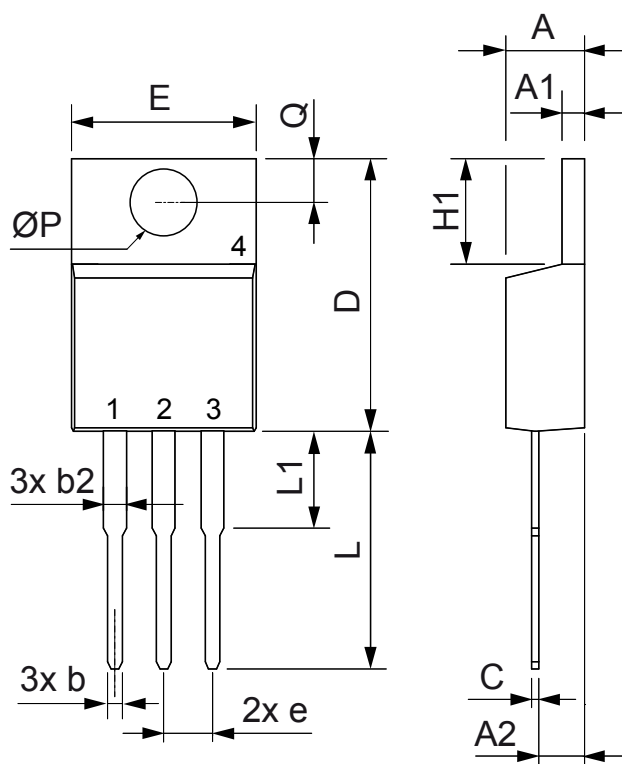
| Similar Part | Package        | Voltage class |
|--------------|----------------|---------------|
| DPG20C200PN  | TO-220ABFP (3) | 200           |

### Equivalent Circuits for Simulation

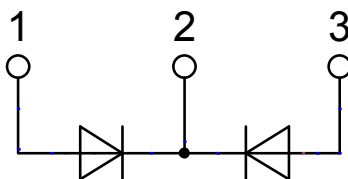
\* on die level

$T_{VJ} = 175\text{ °C}$



**Outlines TO-220**


| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 4.32       | 4.82  | 0.170  | 0.190 |
| A1   | 1.14       | 1.39  | 0.045  | 0.055 |
| A2   | 2.29       | 2.79  | 0.090  | 0.110 |
| b    | 0.64       | 1.01  | 0.025  | 0.040 |
| b2   | 1.15       | 1.65  | 0.045  | 0.065 |
| C    | 0.35       | 0.56  | 0.014  | 0.022 |
| D    | 14.73      | 16.00 | 0.580  | 0.630 |
| E    | 9.91       | 10.66 | 0.390  | 0.420 |
| e    | 2.54       | BSC   | 0.100  | BSC   |
| H1   | 5.85       | 6.85  | 0.230  | 0.270 |
| L    | 12.70      | 13.97 | 0.500  | 0.550 |
| L1   | 2.79       | 5.84  | 0.110  | 0.230 |
| ØP   | 3.54       | 4.08  | 0.139  | 0.161 |
| Q    | 2.54       | 3.18  | 0.100  | 0.125 |



## Fast Diode

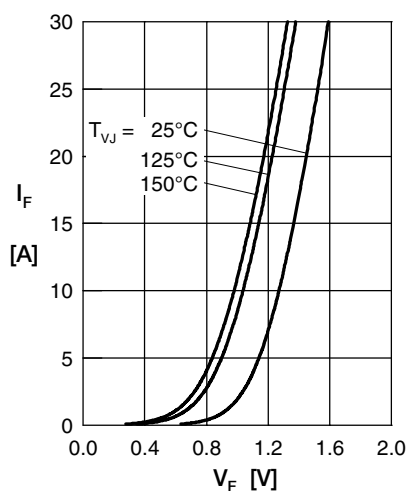


Fig. 1 Forward current  $I_F$  versus  $V_F$

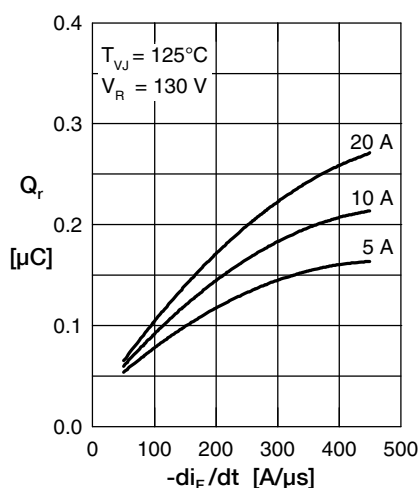


Fig. 2 Typ. reverse recov. charge  $Q_r$  versus  $-di_F/dt$

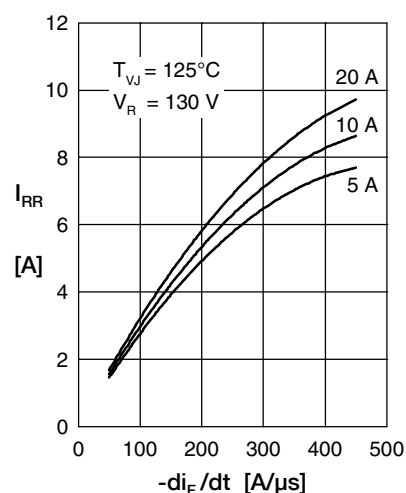


Fig. 3 Typ. reverse recovery current  $I_{RR}$  versus  $-di_F/dt$

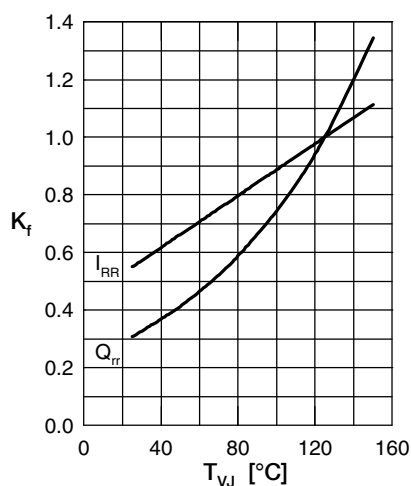


Fig. 4 Typ. dynamic parameters  $Q_{rr}$ ,  $I_{RR}$  versus  $T_{VJ}$

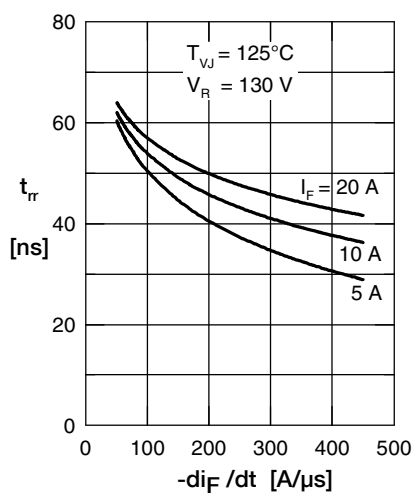


Fig. 5 Typ. reverse recov. time  $t_{rr}$  versus  $-di_F/dt$

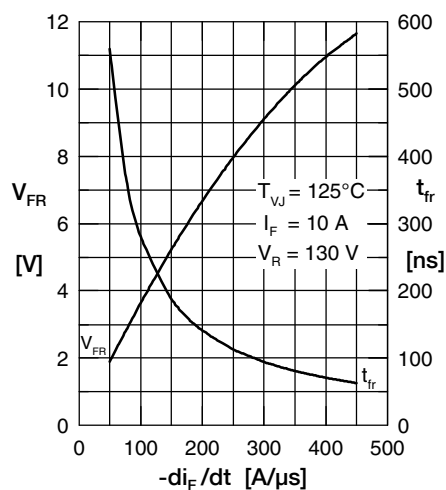


Fig. 6 Typ. forward recovery voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

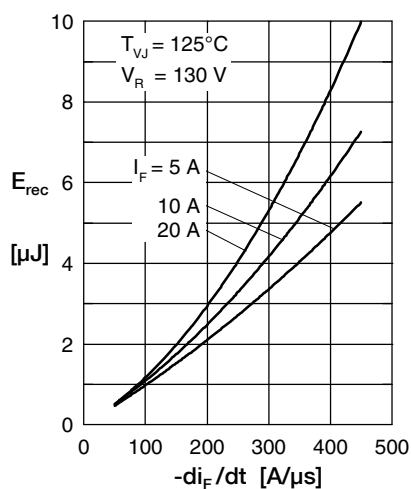


Fig. 7 Typ. recovery energy  $E_{rec}$  versus  $-di_F/dt$

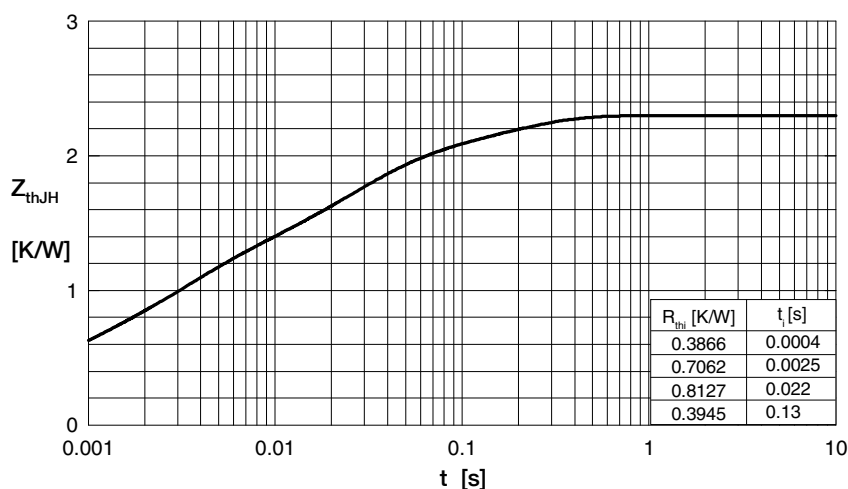


Fig. 8 Transient thermal resistance junction to case